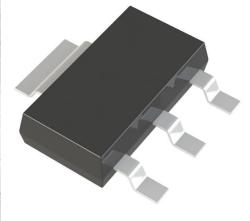


# **FZT792ATC Datasheet**

www.digi-electronics.com



DiGi Electronics Part Number	FZT792ATC-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	FZT792ATC
Description	TRANS PNP 70V 2A SOT223-3
Detailed Description	Bipolar (BJT) Transistor PNP 70 V 2 A 160MHz 2 W S urface Mount SOT-223-3

https://www.DiGi-Electronics.com



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RFQ Email: Info@DiGi-Electronics.com

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# Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
FZT792ATC	Diodes Incorporated
Series:	Product Status:
	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
PNP	2 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
70 V	500mV @ 200mA, 2A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
100nA (ICBO)	300 @ 10mA, 2V
Power - Max:	Frequency - Transition:
2 W	160MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-261-4, TO-261AA	SOT-223-3
Base Product Number:	
FZT792	

# **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Affected	EAR99
HTSUS:	
8541.29.0075	





FZT792A

#### Features

- BV<sub>CEO</sub> > -70V
- I<sub>C</sub> Max. -2A High Continuous Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < -500mV @ -1A</li>
- Complementary NPN Type: FZT692B
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

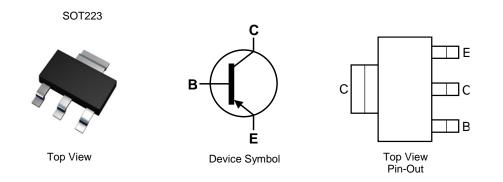
#### 70V PNP MEDIUM POWER TRANSISTOR IN SOT223

## **Mechanical Data**

- Package: SOT223 (Type DN)
- Package Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>(2)</sup>
- Weight: 0.112 grams (Approximate)

#### Applications

Battery-powered circuits



#### Ordering Information (Note 4)

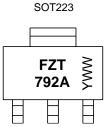
Orderable	derable Part Number	Marking	Reel Size (inches)	b) Tape Width (mm)	Pack	king
Orderable	rait number	Marking	Reel Size (Inches)	rape width (mm)	Quantity	Carrier
FZT7	92ATA	FZT792A	7	12	1,000	Reel

EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied..
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



FZT 792A = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 2 = 2022) WW or  $\overline{W}W$  = Week Code (01~53)



## Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-75	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-70	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	I <sub>C</sub>	-2	A
Peak Pulse Current	Ісм	-5	A

#### Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
	(Note 5)		3.0		
Devues Dissis ation	(Note 6)	D	2.0	w	
Power Dissipation	(Note 7)	PD	1.6	vv	
	(Note 8)		1.2		
	(Note 5)	R <sub>θJA</sub>	41.7		
Thermal Desistance Junction to Ambient	(Note 6)		62.5		
Thermal Resistance, Junction to Ambient	(Note 7)		78.1	°C/W	
	(Note 8)		104		
Thermal Resistance Junction to Lead	(Note 9)	$R_{ ext{ heta}JL}$	12.9		
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

#### ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.

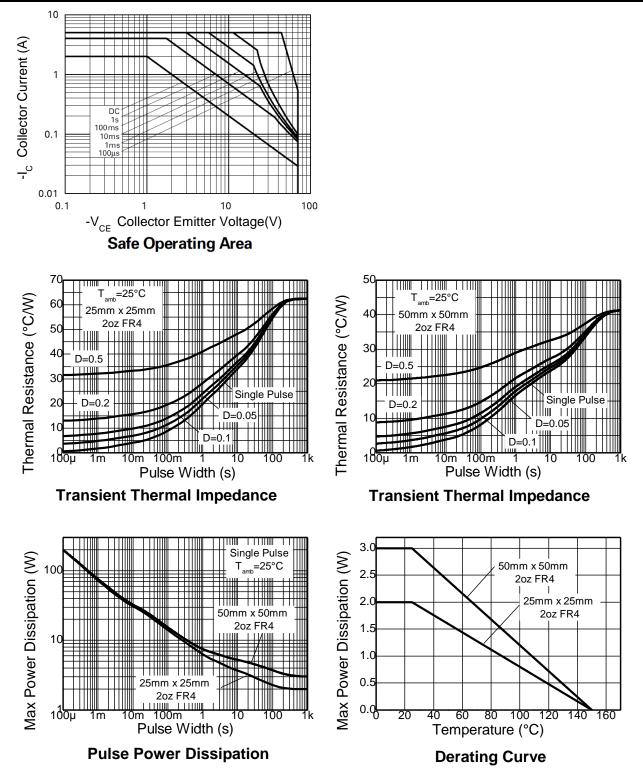
7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.

8. Same as Note 5, except the device is mounted on minimum recommended pad layout.

Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics and Derating Information**





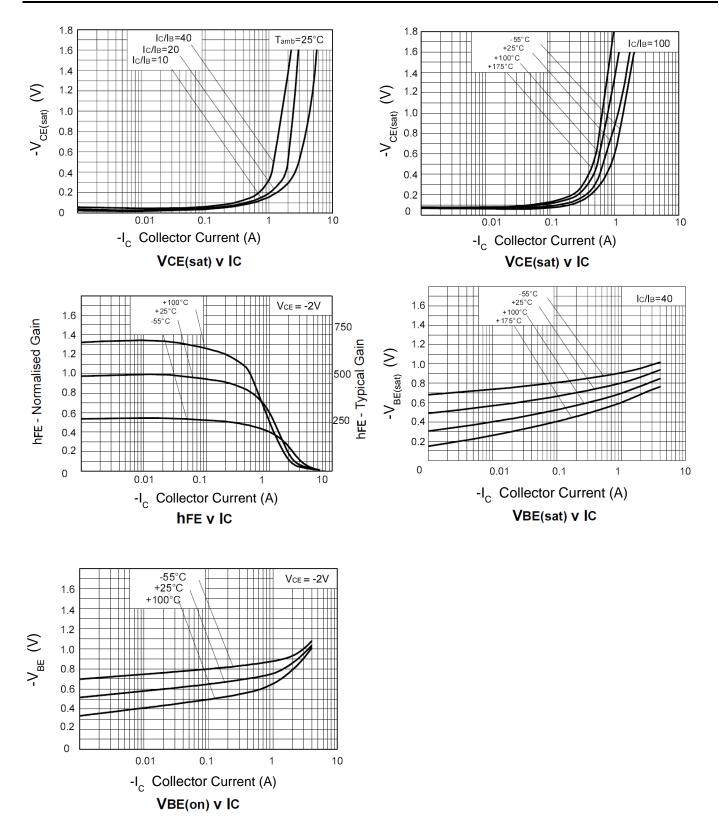
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-75	-100	-	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	-70	-90	-	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.5	-	V	I <sub>E</sub> = -100μA
Collector Cut-Off Current		-	1	-100	nA	$V_{CB} = -40V$
	I <sub>CBO</sub>	-	-	-10	μA	$V_{CB} = -40V, T_{amb} = +100^{\circ}C$
Emitter Cut-Off Current	I <sub>EBO</sub>	-	1	-100	nA	$V_{EB} = -4V$
		-	-0.30	-0.45		I <sub>C</sub> = -500mA, I <sub>B</sub> = -5mA
Collector-Emitter Saturation Voltage (Note 11)	V <sub>CE(sat)</sub>		-0.30	-0.50	V	I <sub>C</sub> = -1A, I <sub>B</sub> = -25mA
		-	-0.30	-0.50		I <sub>C</sub> = -2A, I <sub>B</sub> = -200mA
Base-Emitter Saturation Voltage (Note 11)	V <sub>BE(sat)</sub>	-	-0.80	-0.95	V	I <sub>C</sub> = -1A, I <sub>B</sub> = -25mA
Base-Emitter Turn-On Voltage (Note 11)	V <sub>BE(on)</sub>	-	-0.75	-	V	$I_{C} = -1A, V_{CE} = -2V$
		300	-	800		$I_{C} = -10 \text{mA}, V_{CE} = -2 \text{V}$
DC Current Gain (Note 11)	h <sub>FE</sub>	250	-	-	_	$I_{C} = -500 \text{mA}, V_{CE} = -2 \text{V}$
		200	-	-		$I_{C} = -1A, V_{CE} = -2V$
Current Gain-Bandwidth Product	f <sub>T</sub>	100	160	-	MHz	$V_{CE} = -5V$ , $I_C = -50mA$ f = 50MHz
Turn-On Time	t <sub>on</sub>	-	35	-	ns	V <sub>CC</sub> = -10V, I <sub>C</sub> = -500mA
Turn-Off Time	t <sub>off</sub>	-	750	_	ns	$I_{B1} = -I_{B2} = -50 \text{mA}$
Input Capacitance	C <sub>ibo</sub>	_	225	_	pF	$V_{EB} = -0.5V, f = 1MHz$
Output Capacitance	Cobo	-	25	-	pF	$V_{CB} = -10V, f = 1MHz$

Note: 11. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



## Typical Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

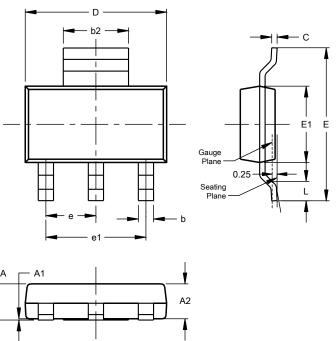


SOT223 (Type DN)



# **Package Outline Dimensions**

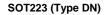
Please see http://www.diodes.com/package-outlines.html for the latest version.

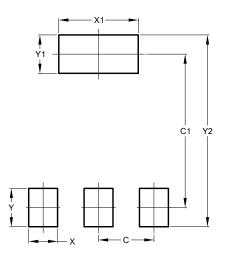


SOT223 (Type DN)						
Dim	Min	Max	Тур			
Α		1.70				
A1	0.01	0.15				
A2	1.50	1.68	1.60			
b	0.60	0.80	0.70			
b2	2.90	3.10				
С	0.20	0.32				
D	6.30	6.70				
ш	6.70	7.30				
E1	3.30	3.70				
е			2.30			
e1			4.60			
L	0.85					
All D	Dimens	ions in	mm			

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

# **↓** | / \_\_\_\_\_



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